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A 0D hybrid lead-free halide with near-unity photoluminescence quantum yield toward multifunctional optoelectronic applications†

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Zero-dimensional (0D) hybrid metal halides have emerged as highly efficient luminescent materials, but integrated multifunction in a structural platform remains a significant challenge. Herein, a new hybrid 0D indium halide of (Im-BDMPA)InCl₆·H₂O was designed as a highly efficient luminescent emitter and X-ray scintillator toward multiple optoelectronic applications. Specifically, it displays strong broadband yellow light emission with near-unity photoluminescence quantum yield (PLQY) through Sb³⁺ doping, acting as a down-conversion phosphor to fabricate high-performance white light emitting diodes (WLEDs). Benefiting from the high PLQY and negligible self-absorption characteristics, this halide exhibits extraordinary X-ray scintillation performance with a high light yield of 55 320 photons per MeV, which represents a new scintillator in 0D hybrid indium halides. Further combined merits of a low detection limit (0.0853 μGy_{air} s⁻¹), ultra-high spatial resolution of 17.25 lp per mm and negligible afterglow time (0.48 ms) demonstrate its excellent application prospects in X-ray imaging. In addition, this 0D halide also exhibits reversible luminescence off-on switching toward tribromomethane (TBM) but fails in any other organic solvents with an ultra-low detection limit of 0.1 ppm, acting as a perfect real-time fluorescent probe to detect TBM with ultrahigh sensitivity, selectivity and repeatability. Therefore, this work highlights the multiple optoelectronic applications of 0D hybrid lead-free halides in white LEDs, X-ray scintillation, fluorescence sensors, etc.

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Introduction

In the past several decades, halide perovskite nanocrystals (PNCs) of CsPbX₃ (X = Cl, Br, I) have emerged as new-generation optoelectronic functional materials due to excellent optical and electronic properties including direct bandgaps, high absorption coefficients, low defect densities, long carrier diffusion lengths, etc.^{1–4} PNCs display excellent photoluminescence (PL) performance with diversified advantages of an adjustable emission wavelength covering the whole visible spectrum, narrow bandwidth, high photoluminescence quantum yield (PLQY), etc.^{5–8} Therefore, three-dimensional (3D) PNCs have been explored as down-conversion phosphors to fabricate solid-

state LED and backlit liquid-crystal display (LCD) devices with high external quantum efficiency and a wide color gamut, respectively.^{9–11} Since 2018, 3D PNCs have been explored as new a kind of scintillator due to their strong X-ray absorption and conversion ability, which aroused new research interest to explore their application in radiation detection and X-ray imaging.^{12,13} In addition, the unique crystal structure and dynamic ionic bond nature also endow 3D PNCs with a PL switching phenomenon as fluorescence sensors toward external stimuli.^{14–16} As a consequence, 3D PNCs possess widely advanced application prospects in LEDs, photovoltaic cells, photodetectors, lasers, scintillators, fluorescent probes, etc.^{17–19} Despite multiple optoelectronic performances, some inescapable shortcomings (such as spectral instability, toxic Pb²⁺ ions, low scintillation light yield, irreversible PL switching, etc.) remain, seriously restricting the application prospects of 3D PNCs, which inspire further in-depth research to explore new environmentally friendly perovskite derivatives to overcome these drawbacks.

Recently, organic-inorganic hybrid zero-dimensional (0D) metal halide perovskites have attracted tremendous attention as some of the promising candidates of 3D PNCs with comparable optoelectronic properties and superior stabilities.^{20–23} Indeed, versatile organic species and substantial metal ions

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In view of these shortcomings, we focus on this domain to explore highly efficient emissive 0D hybrid indium halides

Bulk single crystals of (Im-BDMPA)InCl₆·H₂O were prepared via a typical low-temperature solvothermal reaction method. Based on single crystal X-ray diffraction, the structure of (Im-BDMPA)InCl₆·H₂O crystallizes in the orthorhombic space group *P*2₁2₁ and composed of discrete [InCl₆]³⁻ octahedra surrounded by bulk (Im-BDMPA)³⁺ cations. All the In³⁺ ions are surrounded by six Cl⁻ ions in [InCl₆]³⁻ octahedra with In-Cl bond distances in the normal range of 2.5009(6)-2.5452(6) Å (Fig. 1a). All the neighboring [InCl₆]³⁻ octahedrons are separated by long (Im-BDMPA)³⁺ cations to form a 0D hydrogen bonding structure at the molecular level (Fig. 1b). The sample purity and high crystalline degree of (Im-BDMPA)InCl₆·H₂O are revealed by matched experimental and simulated powder X-ray diffraction (PXRD) patterns (Fig. 1c). The distributions of the respective chemical compositions have been checked using energy dispersive X-ray spectroscopy (EDS), elemental mapping images, *etc.* (Fig. S1† and 1d). Sb³⁺-doped (Im-BDMPA)InCl₆·H₂O was synthesized by adding the desired amount of SbCl₃ into the original synthesis process of the single indium phase, and the coincident PXRD pattern indicates the same crystal structure (Fig. 1c). The chemical composition and successful Sb doping were further confirmed by EDS and elemental mapping, and the optimized doping concentration of Sb element was determined to be 22% by inductively coupled plasma optical emission spectroscopy (ICP-OES) (Fig. S2† and 1d). Subsequently, high-quality (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O microcrystals were synthesized as an example through a microwave irradiation assisted mechanical stripping method and finally shows a nearly cubic shape with a particle size less than <5 μm (Fig. 1e). The identical diffraction peaks in the PXRD pattern

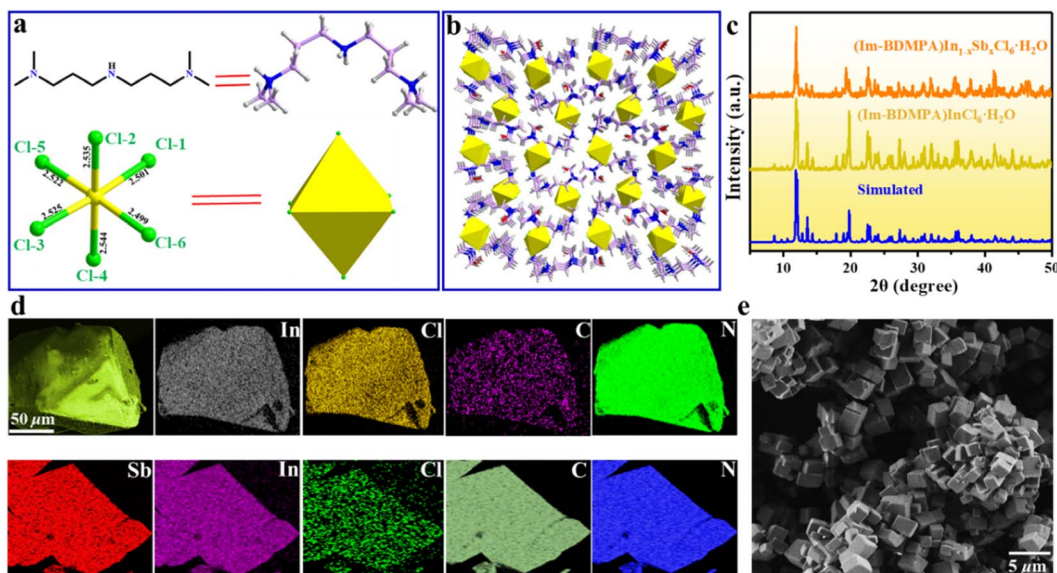


Fig. 1 Structural characterization of $(\text{Im-BDMPA})\text{In}_{1-x}\text{Sb}_x\text{Cl}_6\cdot\text{H}_2\text{O}$: (a) $(\text{Im-BDMPA})^{3+}$ cation and $[\text{In/SbCl}_6]^{3-}$ octahedron; (b) packing structure of the 0D structure viewed along the a -axis; (c) simulated and experimental PXRD patterns; (d) elemental mapping of SEM images; (e) SEM image of a microparticle.

indicate the high crystalline degree of microcrystals (Fig. S3†). $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6\cdot\text{H}_2\text{O}$ microcrystals can also be prepared by a solid-phase mechanochemical grinding method from precursor materials within a fast time of 30 s and with 100% yield verified by the same PXRD pattern, providing a facile

preparation method for various optoelectronic device engineering (Fig. S4 and S5†).

As shown in Fig. 2a and S6,† bulk single crystals of pristine and doped $(\text{Im-BDMPA})\text{InCl}_6\cdot\text{H}_2\text{O}$ display the same bright yellow light emission under UV light radiation. The PL properties of $(\text{Im-BDMPA})\text{InCl}_6\cdot\text{H}_2\text{O}$ are summarized in Fig. S6,† and

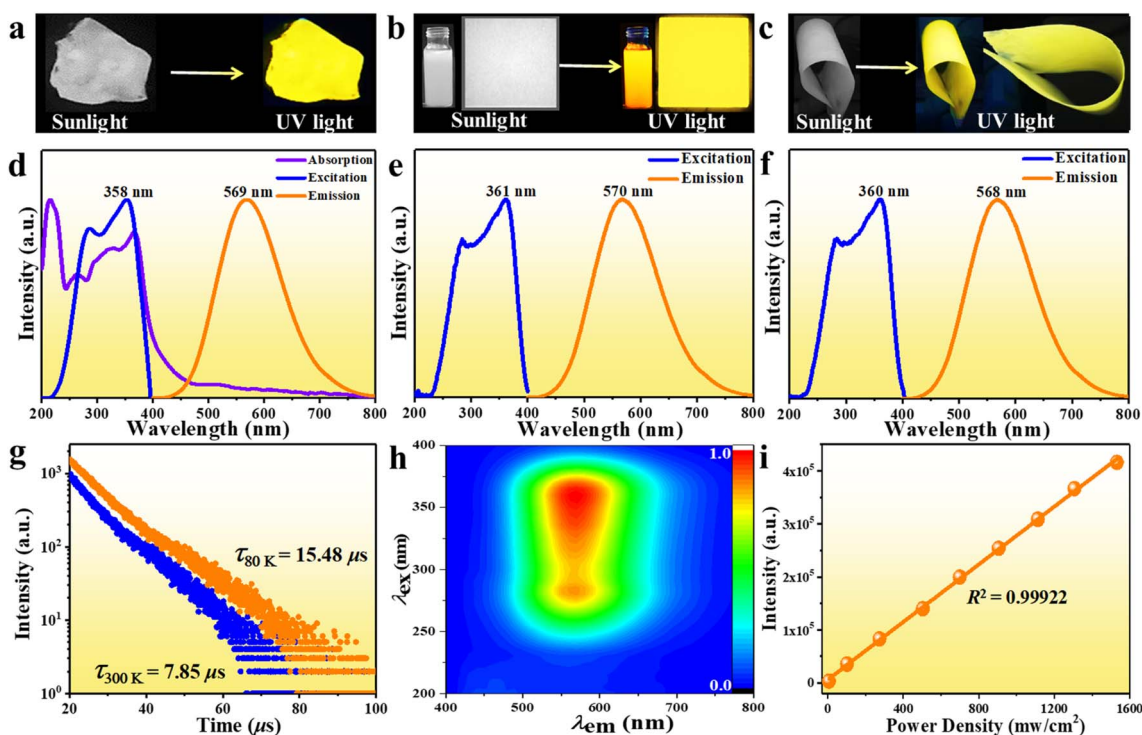


Fig. 2 PL characterization of $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6\cdot\text{H}_2\text{O}$: (a–c) photo images of bulk crystals, microparticles, the deposited thin film and the flexible composite film under sunlight and 365 nm UV light; (d–f) absorption, excitation and emission spectra of bulk crystals, microparticles and flexible composite; (g) PL decay curves at 300 K and 80 K; (h) 3D consecutive PL map; (i) power density dependent PL emission intensity.



shift, wide FWHM and long lifetime should originate from the radiative recombination of STEs due to the strong electron-phonon (EP) coupling effect in the deformable 0D soft crystal lattice.^{28,29}

To probe into the underlying PL mechanism and confirm the STE nature, temperature dependent PL emission spectra were recorded from 300 to 80 K (Fig. S14a[†]). As shown in Fig. 3a, a new weak emission band emerges in the temperature decreasing process, which can be ascribed to be singlet STE. The maximum emission wavelength exhibits a slightly red shift from 558 nm to 570 nm along with the temperature increasing, which is mainly determined by EP interaction based on the theoretical fitting of temperature dependent emission energy evolution (Fig. S14b[†]). In the temperature decreasing process, the emission intensity increases monotonously from 300 to 80 K owing to decreased thermal quenching and nonradiative recombination rates. Thermal activation energy (E_a) can be extracted by fitting the temperature dependent integrated emission intensity to the Arrhenius equation, which represents the energy barrier of excitons between radiative and non-radiative centers. The calculated E_a of 43 meV is larger than the thermal dissociation energy (~ 26 meV) of free excitons at 300 K, indicating the formation of stable bound excitons for (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O (Fig. 3b). Simultaneously, the emission spectra gradually broaden along with the increasing temperature due to enhanced EP coupling. To accurately evaluate the strength of the EP effect, the temperature dependent FWHM is fitted by using the following equation (1):

$$\Gamma(T) = \Gamma_0 + \Gamma_{\text{phonon}} \left(e^{\frac{E_{\text{LO}}}{k_B T}} - 1 \right)^{-1} + \Gamma_{\text{in homo}} e^{-\frac{E_b}{k_B T}} \quad (1)$$

where Γ_0 is the FWHM of 0 K, and E_{LO} and E_{b} represent the energy of the longitudinal-optical phonon and average binding energy of the trap states, respectively. Γ_{phonon} and Γ_{inhomo} represent the relative contributions of EP coupling and inhomogeneous broadening induced by trapped states, respectively.⁴⁶ As shown in Fig. 3c, the best fitting of the FWHM demonstrates the major contribution of EP coupling ($\Gamma_{\text{phonon}} = 31$ meV) compared to the inhomogeneous broadening effect. The calculated phonon energy (E_{LO}) of 17 meV corresponds to In/Sb-Cl stretching frequency (158 cm^{-1}) in the Raman spectrum, confirming EP coupling in the deformable crystal lattice (Fig. S15[†]). In addition, the deformability of the soft crystal lattice can be evaluated by using the Huang-Rhys factor (S) according to the following equation (2):

$$\text{FWHM} = 2.36\sqrt{S\hbar\omega_{\text{photon}}}\sqrt{\coth\frac{\hbar\omega_{\text{photon}}}{2k_{\text{B}}T}} \quad (2)$$

where $\hbar\omega_{\text{photon}}$ is the phonon vibration energy. By fitting the temperature dependence of the FWHM, the obtained S factor of 37 is much higher than those of traditional semiconducting materials, such as CdSe (1.0), ZnSe (0.3), CsPbX₃ (3.2), *etc.*, demonstrating the soft crystal nature and easy formation of STE (Fig. 3d).^{47–49} Therefore, the broad light emission of (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O can be ascribed to the radiative



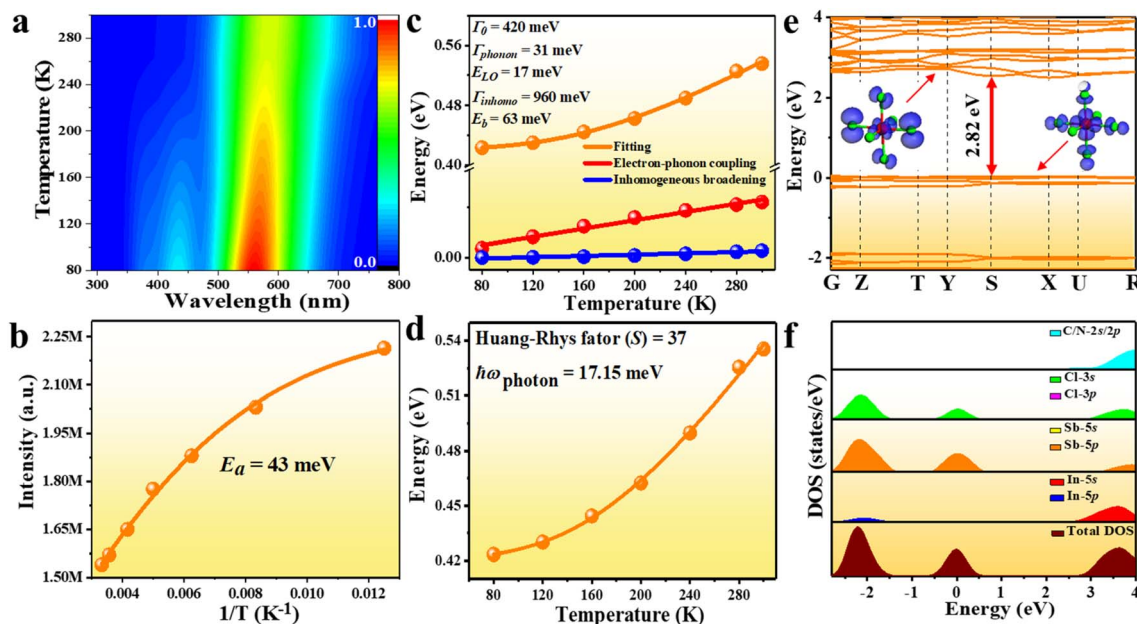


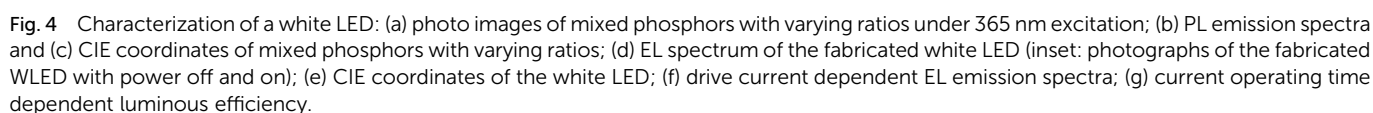
Fig. 3 PL mechanism study of $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$: (a) 3D color mapping of PL emission at varied temperature; (b) experimental and fitted emission intensity vs. reciprocal temperature; (c) temperature-dependent FWHM with the contribution of electron–phonon coupling and inhomogeneous broadening; (d) fitted FWHM according to eqn (2); (e) electronic band structure (inset: electron density maps of the HOMO and LUMO); (f) total and partial densities of states.

recombination of STE due to EP coupling in the soft crystal lattice. The detailed PL mechanism was further unveiled by using density functional theory (DFT) calculations. As shown in Fig. S16† and 3e, the incorporation of Sb^{3+} into pure 0D indium perovskite induces an isolated and extremely narrow impurity band in valence bands, which reduces the band gap from 4.2 eV to 2.82 eV. Owing to the absence of electronic interactions between adjacent anionic octahedra, both the conduction and valence bands are fairly flat illustrating highly localized electron states with large effective mass, promoting the formation of electron and hole polarons.⁵⁰ However, the conduction bands remain unchanged meaning that the incorporation of Sb^{3+} mainly leads to up-shift of the VBM. Detailed density of states and electron maps show that both the CBM and VBM are contributed by anionic species without direct contribution from the organic component (Fig. 3e and f). Therefore, the corporation of Sb^{3+} does not influence the radiative recombination process but introduces new impurity bands, increases the electron state density of VBM, facilitates more carriers into the conduction band, and finally improves the emission efficiency.⁵¹

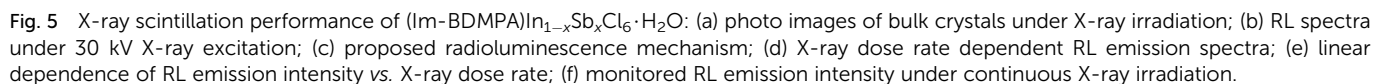
Apart from the highly efficient broadband light emission, $(\text{Im-BDMPA})\text{In}_{1-x}\text{Sb}_x\text{Cl}_6 \cdot \text{H}_2\text{O}$ also exhibits sufficient structural and spectral stability. Based on thermogravimetric analysis, the bulk crystals of $(\text{Im-BDMPA})\text{In}_{1-x}\text{Sb}_x\text{Cl}_6 \cdot \text{H}_2\text{O}$ can be stable up to about 280 °C (Fig. S17†). Under continuous heating at different temperatures from 80 °C to 280 °C, the PL emission spectral profiles remain unchanged with slightly decreased intensities and PXRD patterns are also fixed indicating sufficient thermal stability (Fig. S18†). After long-term exposure to humid air for one month or strong UV light for 48 h, $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$

retains the high crystalline degree and nearly identical emission intensity (Fig. S19†). Highly efficient and stable broadband (FWHM = 135 nm) yellow light emission motivates us to fabricate a white LED by using $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ as a down-conversion phosphor. To validate this application, we firstly blend $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ as a yellow phosphor and commercial $\text{BaMgAl}_{10}\text{O}_{17}:\text{Eu}^{2+}$ as a blue phosphor with varied ratios. As shown in Fig. 4a and b, the mechanically mixed phosphors display white light emission under irradiation of 365 nm UV light and broadband PL spectra are composed of dual blue-yellow emitting peaks. By finely controlling the blending ratio of the two phosphors, a range of “cold” to “warm” white light can be obtained with tunable correlated color temperature (CCT) from 9520 K to 3320 K (Fig. 4c and Table S2†). Subsequently, a white LED was fabricated as an example by coating the mixed phosphor on an UV chip. Under the drive of 20 mA current, the LED gives bright white light with a CCT of 4590 K and CIE chromaticity coordinates of (0.35, 0.33) (Fig. 4d and e). The obtained color rendering (CRI) index of 95.4 is far higher than that of commercially available white LEDs based on $\text{YAG}:\text{Ce}^{3+}$ (CRI < 80).³¹ To test the reabsorption effect between the two phosphor counterparts, varied electroluminescence (EL) spectra under different operating currents were recorded (Fig. 4f). With the current increasing from 20 mA to 120 mA, both the EL emission intensities of dual emission peaks increase linearly with enhanced drive current without energy transfer between the two phosphors, showcasing potential application in high-power white LEDs. The CIE coordinates, CCT and CRI also keep almost unchanged indicating the negligible self-absorption and efficiency loss of the fabricated





The high PLQY, broad emission band and large Stokes shift demonstrate the potential of (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O as a promising candidate of X-ray scintillators. We firstly plot the absorption spectra of (Im-BDMPA)In_{1-x}Sb_xCl₆·H₂O and commercial Ce:LuAG toward X-ray in a broad range of photon energy based on the photon cross-section database (Fig. S21†). Based on the calculation of the X-ray absorption coefficients (α)



versus a broad range of photon energies, the X-ray attenuation efficiencies of $(\text{Im-BDMPA})\text{In}_{1-x}\text{Sb}_x\text{Cl}_6 \cdot \text{H}_2\text{O}$ are comparable with that of Ce:LuAG in the region of medical digital radiography (18–30 keV). Under the irradiation of 30 kV X-rays, bulk crystals of $(\text{Im-BDMPA})\text{In}_{1-x}\text{Sb}_x\text{Cl}_6 \cdot \text{H}_2\text{O}$ display bright yellow light as shown in Fig. 5a, and the detailed scintillation properties are further determined by using Ce:LuAG as a standard reference. Both $(\text{Im-BDMPA})\text{In}_{1-x}\text{Sb}_x\text{Cl}_6 \cdot \text{H}_2\text{O}$ samples display broad radioluminescence (RL) emission bands centered at 570 nm, which are similar to those under UV excitation indicating the same radiative recombination pathway (Fig. 5b). Based on a previous study, the photoelectric effect occurs between the interaction of X-ray phonon and electrons in the inner shell of atoms, generating higher-energy electrons and holes (Fig. 5c). The created hot carriers further lose energy through thermal relaxation into valence and conduction band edges as secondary electrons and holes. Subsequently, the generated electron-hole polarons undergo thermalization to form free excitons (FEs), which transfer to STEs through intersystem crossing to generate broadband emission.¹²

Although the RL emission intensity of $(\text{Im-BDMPA})\text{InCl}_6 \cdot \text{H}_2\text{O}$ is lower than that of Ce:LuAG , the Sb^{3+} -doped strategy greatly enhances the X-ray response up to about 2.2 times that of Ce:LuAG . By integrating the peak area of RL emission spectra, the light yields of $(\text{Im-BDMPA})\text{InCl}_6 \cdot \text{H}_2\text{O}$ and $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ are derived to be about 23 047 and 55 320 photons per MeV on the basis of Ce:LuAG (25 000 photons per MeV). Herein, it is noteworthy that $(\text{Im-BDMPA})\text{In}_{1-x}\text{Sb}_x\text{Cl}_6 \cdot \text{H}_2\text{O}$ represents a rare X-ray scintillator in 0D indium halides, which opens a new window to explore promising candidates for

scintillators (Table S4†). Significantly, the light yield of $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ exceeds that of most of the state-of-the-art commercial scintillators including CsI:Tl (54 000 photons per MeV), CsI:Na (41 000 photons per MeV), CdWO_4 (20 000 photons per MeV), LYSO (33 200 photons per MeV), *etc.*^{35,50–52} Additionally, the scintillation light yield is also superior to those of most halide scintillators, such as 3D CsPbBr_3 (~21 000 photons per MeV), $(\text{PPN})_2\text{SbCl}_5$ (49 000 photons per MeV), Cs_3MnI_5 (33 600 photons per MeV), $(\text{DIET})_3\text{Cu}_3\text{Br}_3$ (20 000 photons per MeV), *etc.*^{34,53–55} Such outstanding scintillation performance is related to the high X-ray attenuation efficiency, near unity PLQY and large Stokes shift. To investigate the detection sensitivity of this 0D halide toward X-rays, RL emission spectra were collected at various X-ray dose rates. As shown in Fig. 5d, $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ displays the same RL emission spectral profiles with monotonously enhanced emission response to the increase of the dose rate from 4101.5 $\mu\text{Gy s}^{-1}$ to 43 577.8 $\mu\text{Gy s}^{-1}$. The best linear fitting between RL emission intensity and dose rate gives an ultralow detection limit of 0.0853 $\mu\text{Gy s}^{-1}$ when the signal-to-noise ratio (SNR) is 3, which is much lower than the required value for regular medical diagnostics (5.5 $\mu\text{Gy s}^{-1}$) (Fig. 5e). In addition, the radiant stability against X-ray illumination is also a crucial indicator for evaluating the performance of X-ray scintillators. Under continuous X-ray irradiation at a fixed dose rate of 37 mGy s^{-1} over 30 hours, the RL emission intensity of $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ features negligible fluctuation and attenuation demonstrating robust stability for X-rays (Fig. 5f).

Combined superiorities of a high light yield, ultralow detection limit and sufficient X-ray endurance provide the

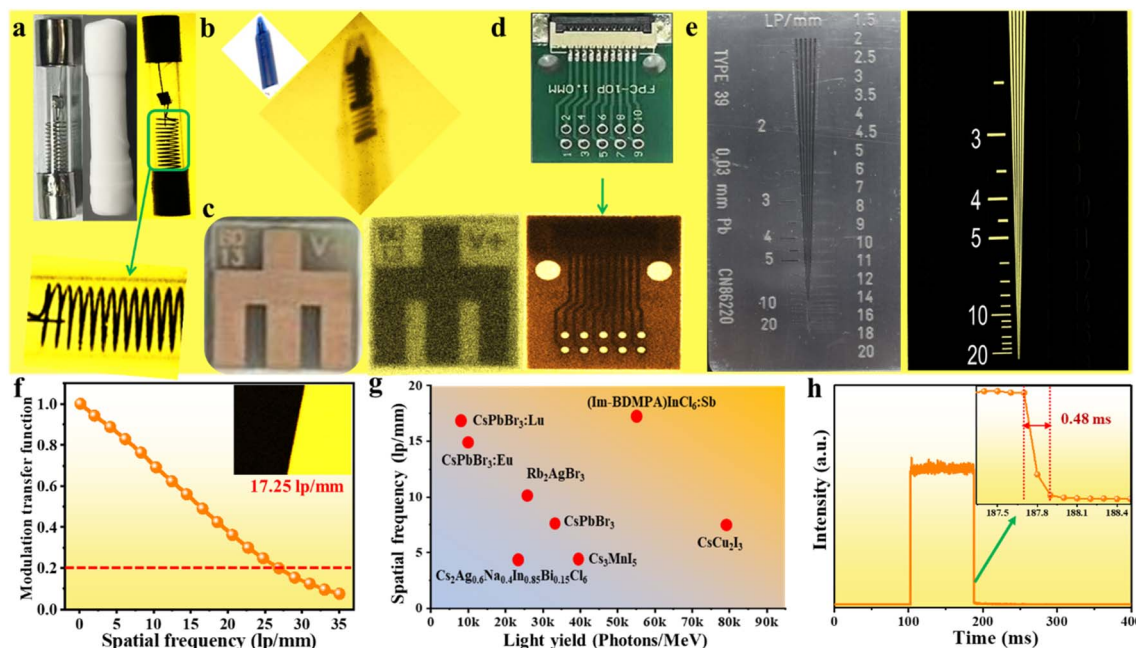


Fig. 6 Applications of X-ray imaging based on the $(\text{Im-BDMPA})\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ screen under 50 kV X-ray irradiation: photographs and X-ray imaging of (a) an encapsulated fuse tube, (b) ball pen containing metallic spring, (c) metallic device and (d) electronic chip; (e) photograph (left) and X-ray image (right) of the standard X-ray test pattern plate; (f) modulation transfer function (MTF) curve on the X-ray image of a slanted-edge; (g) comparison of the light yield and spatial frequency of metal halide scintillations; (h) X-ray induced afterglow profile.

feasibility of applications in X-ray imaging. As a proof of concept, we employed X-ray imaging by using an (Im-BDMPA) $\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ based thin screen on a home-made X-ray imaging optical system, and a series of small devices are selected as target objects. As shown in Fig. 6a, an encapsulated fuse tube containing wire was exposed to X-ray illumination, and the different X-ray absorption abilities of the wire and glass tube result in bright spatial intensity contrast, which is translated by the scintillation screen to form optical images with the assistance of a digital camera. Therefore, the inside wire clearly appears in an optical image by using the (Im-BDMPA) $\text{In}_{1-x}\text{Sb}_x\text{Cl}_6 \cdot \text{H}_2\text{O}$ screen. Similarly, when a ball pen containing metallic spring, metallic device and electronic chip were exposed to X-ray irradiation, all the metallic components can be clearly seen in optical images with an enough contrast ratio on the scintillation screen (Fig. 6b–d).

To obtain the spatial resolution of the scintillation screen, a standard X-ray resolution test pattern plate was adopted to perform the X-ray imaging and the observation limit is almost 20 lp per mm (Fig. 6e). The modulation transfer function (MTF) of the scintillation screen was further employed on the X-ray image of a slanted-edge to obtain more accurate spatial resolution (Fig. 6f). The spatial resolution of the screen is extracted to be 17.25 lp per mm when MTF is equal to 0.2, which is obviously superior to that of commercial $\text{CsI}(\text{Tl})$ (10 lp per mm), and metal halide scintillators of $\text{CsPbBr}_3\text{:Lu}$ (16.8 lp per mm), $\text{CsPbBr}_3\text{:Eu}$ (15 lp per mm), $\text{Ba}_2\text{PbBr}_4\text{:10%Mn}$ (10.7 lp per mm),

Rb_2AgBr_3 (10.2 lp per mm), MAPbBr_3 (9.8 lp per mm), CsCu_2I_3 (7.5 lp per mm), *etc.* (Fig. 6g).^{35,50,56–61} Finally, considering the fact that a long RL emission lifetime would results in a strong image lag or ghosting after ceasing of X-rays, it is important to test the RL afterglow to evaluate the image contrast.^{62,63} As shown in Fig. 6h, the emission intensity of the RL afterglow signal rapidly decreases to zero in 0.48 ms after ceasing of X-ray excitation demonstrating high imaging contrast. Overall, the high spatial resolution and negligible afterglow signal indicate the excellent X-ray imaging performance of the (Im-BDMPA) $\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ based scintillation screen.

The soft and impressible 0D crystal structure of the halide inspires us to further investigate the external stimulus responsive luminescence switching phenomenon toward various small chemical molecules as a possible fluorescent probe. Herein, we select the (Im-BDMPA) $\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$ based thin film as a platform to investigate the PL switching performance, which displays the same luminescence as that of bulk crystals but possesses more operability for sensing applications (Fig. 2f). To validate the sensing performance of (Im-BDMPA) $\text{In}_{0.78}\text{Sb}_{0.22}\text{Cl}_6 \cdot \text{H}_2\text{O}$, the PL emission spectra were monitored before and after exposing the thin film to various organic solvents over several hours. Herein, a series of small halohydrocarbon molecules or derivatives were selected as sensing targets including chloroacetic acid (CAA), dichloroacetic acid (DCAA), chloropropiophenone (CPP), dibromomethane (DBM), bromodichloromethane (BDCM), dichloromethane (DCM),

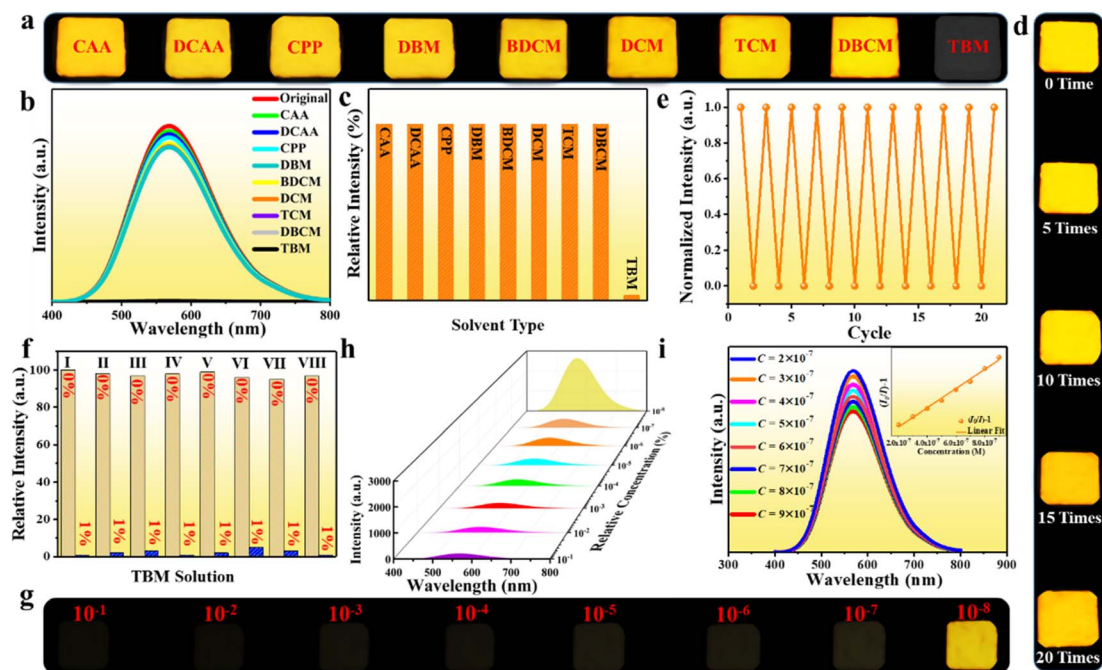


Fig. 7 Application of the fluorescent probe: (a) photo images of the film after exposing to various organic solvents; (b) PL emission spectra and (c) normalized emission intensity of the thin film after exposing to organic solvents; (d) photo images and (e) PL emission intensity of the film during quenching–recovering cycles in TBM as a function of cycle number; (f) normalized luminescence intensity histogram of the film after exposed to mixed solutions of TBM and other organic solvents with concentrations of 0% and 1% (I) CAA; (II) DCAA; (III) CPP; (IV) DBM; (V) BDCM; (VI) DCM; (VII) TCM; (VIII) DBCM); (g) photo images and (h) PL emission spectra of the film after exposing to CTC solutions with low concentrations of TBM from 10^{-1} to 10^{-8} by volume; (i) PL emission spectra of the thin film after soaking in CTC solutions with different concentrations of TBM from 2×10^{-7} to 9×10^{-7} by volume (inset: linear fitting of emission intensity ratio vs. TBM concentration).

trichloromethane (TCM), dibromo-monochloro-methane (DBCM) and tribromomethane (TBM). As shown in Fig. 7a, the photo images of the thin film under UV light irradiation reveal that the fluorescence is rapidly quenched by TBM in less than one second, whereas those of others still exhibit the same bright yellow light luminescence. Detailed PL emission spectra demonstrate that the luminescence intensity of the film in TBM solvent are almost completely quenched, whereas those in other organic solvents are nearly unchanged (Fig. 7b and c). To further inspect the sensing selectivity, substantial organic solvents containing different functional groups were selected as contrast targets including alcohol, acetonitrile, acetone, tetrahydrofuran, acetylacetone, aromatic hydrocarbon (e.g., benzene, dimethylbenzene, chlorobenzene, and nitrobenzene), etc. As shown in Fig. S22,† the (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O films display the same broad yellow emission bands as that of the freshly prepared sample with almost identical emission intensities. These contrast experiments demonstrate that the fluorescence of (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O is solely quenched by TBM but failed for other organic solvents. More excitedly, the quenched fluorescence of the thin film by TBM can be recovered to the original yellow emission after washing with carbon tetrachloride (CTC), and the PL emission intensity can reach up to nearly 100% of original data (Fig. S23†). To more accurately confirm the repeatability of the reversible quenching-recovering process, we monitor the varied PL emission intensity of the (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O film during consecutive impregnation-washing cycles. As shown in Fig. 7d, the thin film displays a repeatable PL quenching-recovering cycle and the luminescence is able to persistently return to the original yellow color after washing with CTC even after consecutive 20 cycles. Simultaneously, the negligible decrease of emission intensity also indicates high reversibility and repeatability (Fig. 7e). After exposing to these organic solvents, the PXRD patterns reveal strong diffraction peaks with a high crystalline degree, indicating a stable crystal structure lattice (Fig. S24–S26†). Therefore, (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O displays reversible TBM responsive fluorescence on/off switching, which indicates the feasibility of the fluorescent probe to detect TBM.

The sharply contrasting response to TBM and other organic solvents inspires us to investigate the selectivity for sensing applications, and a series of anti-interference experiments were performed in mixed solutions of TBM and other halohydrocarbon solvents. As depicted in Fig. S27† and 7f, the PL emission intensities of the film were almost completely quenched after exposing to mixed solutions containing a small amount of TBM (1%) but failed in TBM free solutions, which manifest that (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O possesses an excellent sensing selectivity toward TBM. The sensitivity of the fluorescent probe is another crucial indicator to evaluate the sensing performance in practical applications. To explore the sensitivity of the fluorescent probe, a series of dilute TBM/CTC solutions with very low concentrations from 10^{−1} to 10^{−8} by volume were further blended as representative targets. As shown in Fig. 7g and h, both the photo images and PL emission spectra indicate that the film remains to exhibit the PL

quenching phenomenon when the content of TBM is reduced to 10^{−7} (0.1 ppm). Detailed PL emission spectra toward ultra-dilute TBM/CTC solutions in the concentration range of 2 × 10^{−7} to 9 × 10^{−7} indicate that the fluorescence intensity of the film gradually decreases with the increase of TBM concentration, and the quenching effect ($I_0/I - 1$) is linearly dependent on the TBM concentration with a good linear relation ($R^2 = 0.9998$), indicating excellent detection operability (Fig. 7i). These results demonstrate that (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O is a highly desirable fluorescent probe to detect TBM with high selectivity, sensitivity and repeatability.

To illustrate the quenching mechanism toward TBM, the UV-vis absorption spectra were firstly studied on the sample after immersing in various organic solvents. As shown in Fig. S28,† the absorption spectra do not display any change after soaking in most of the organic solvents, while the TBM-treated sample exhibits a more widespread absorption range from 200 nm to 650 nm, which overlaps partially with the emission spectrum of the as-synthesized sample, indicating significant electron exchange and self-absorption characteristics. To further verify the energy transfer between (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O and TBM, X-ray photoelectron spectroscopy (XPS) was performed at the surface of the sample. Compared with the as-synthesized halide, the binding energies of C-2s and N-2s shift slightly to lower energy, while those of Cl-2p, In-3d and Sb-3d shift to higher energy in the TBM treated halide sample (Fig. S29†). All these investigations indicate the energy transfer between (Im-BDMPA)In_{0.78}Sb_{0.22}Cl₆·H₂O and TBM molecules, which consume drastically the excited carriers and quench the luminescence of the halide, and a similar phenomenon has been confirmed in numerous fluorescent probes.⁶⁴

Conclusions

In summary, we herein demonstrate a new 0D hybrid indium/antimony halide as a highly efficient broadband yellow light emitter with near-unity PLQY and multifunctional applications. Firstly, the broadband emission realizes a high-performance white LED with tunable color temperature. Secondly, this halide represents a new X-ray scintillator in 0D hybrid indium halide with promising X-ray imaging applications, as highlighted by the combined merits of a prominent light yield, low detection limit, ultra-high spatial resolution and negligible afterglow time. Thirdly, reversible TBM responsive luminescence off-on switching enables it to be a perfect real-time fluorescent probe to detect TBM with ultrahigh sensitivity, selectivity and repeatability. Therefore, high-performance multiple optoelectronic applications in white LEDs, X-ray scintillation and fluorescence sensors are synchronously realized in a 0D halide structural platform. These multiple applications benefit from the synergistic effects of intrinsic quantum confinement, strong electron-phonon coupling, the sufficient absorption coefficient of X-ray and the impressible structure in the 0D deformable crystal lattice. This work not only deepens the fundamental understanding of the luminescence properties of 0D hybrid halides but also realizes multiple optoelectronic applications. We believe that this



research would guide the rational design of new 0D hybrid metal halides as advanced luminescent materials in cutting-edge optoelectronic fields.

Data availability

The data that support the finding of this study are available from the corresponding author upon reasonable request.

Author contributions

D.-Y. Li and H.-Y. Kang designed the experiments and carried out material synthesis, Y.-H. Liu and J. Zhang assisted in the measurements, Y.-C. Yue helped in data analysis, and D. Yan and X.-W. Lei were responsible for supervision and revising the manuscript. All authors participated in discussing the data and writing the manuscript.

Conflicts of interest

The authors declare no conflict of interest.

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